

Ordering number:EN1597C

NPN Triple Diffused Planar Silicon Transistor

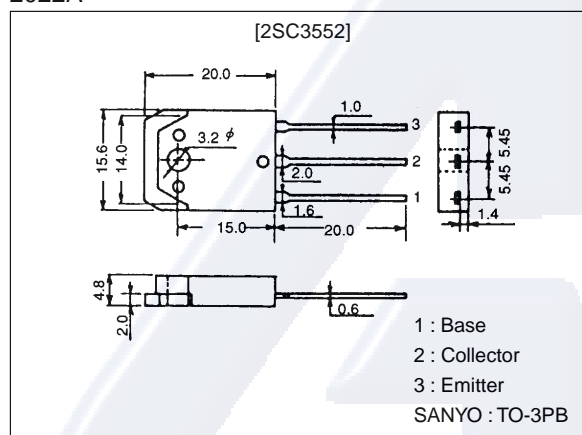
SANYO**2SC3552****800V/12A Switching Regulator Applications****Features**

- High breakdown voltage and high reliability.
- Fast switching speed (t_f : 0.1 μ s typ).
- Wide ASO.
- Adoption of MBIT process.

Package Dimensions

unit:mm

2022A

**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|-----------|---|-------------|------------------|
| Collector-to-Base Voltage | V_{CB0} | | 1100 | V |
| Collector-to-Emitter Voltage | V_{CEO} | | 800 | V |
| Emitter-to-Base Voltage | V_{EBO} | | 7 | V |
| Collector Current | I_C | | 12 | A |
| Collector Current (Pulse) | I_{CP} | $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 10\%$ | 30 | A |
| Base Current | I_B | | 6 | A |
| Collector Dissipation | P_C | $T_c = 25^\circ\text{C}$ | 150 | W |
| Junction Temperature | T_j | | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | | -55 to +150 | $^\circ\text{C}$ |

Electrical Characteristics at $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--------------------------|-----------|---|---------|-----|-----|---------------|
| | | | min | typ | max | |
| Collector Cutoff Current | I_{CBO} | $V_{CB}=800\text{V}$, $I_E=0$ | | | 10 | μA |
| Emitter Cutoff Current | I_{EBO} | $V_{EB}=5\text{V}$, $I_C=0$ | | | 10 | μA |
| DC Current Gain | h_{FE1} | $V_{CE}=5\text{V}$, $I_C=0.8\text{A}$ | 10* | | 40* | |
| | h_{FE2} | $V_{CE}=5\text{V}$, $I_C=4\text{A}$ | 8 | | | |
| Gain-Bandwidth Product | f_T | $V_{CE}=10\text{V}$, $I_C=0.8\text{A}$ | | 15 | | MHz |
| Output Capacitance | C_{ob} | $V_{CB}=10\text{V}$, $f=1\text{MHz}$ | | 215 | | pF |

* : The h_{FE1} of the 2SC3552 is classified as follows. When specifying the h_{FE1} rank, specify two ranks or more in principle.

| | | | | | | | | |
|----|---|----|----|---|----|----|---|----|
| 10 | K | 20 | 15 | L | 30 | 20 | M | 40 |
|----|---|----|----|---|----|----|---|----|

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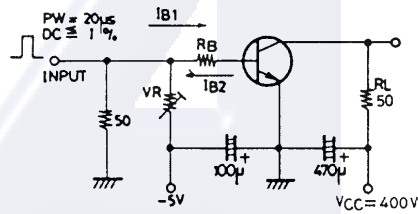
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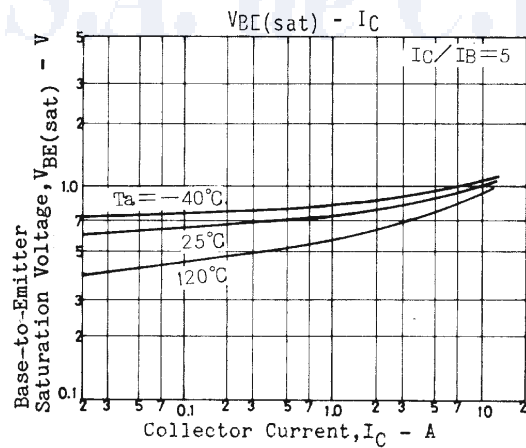
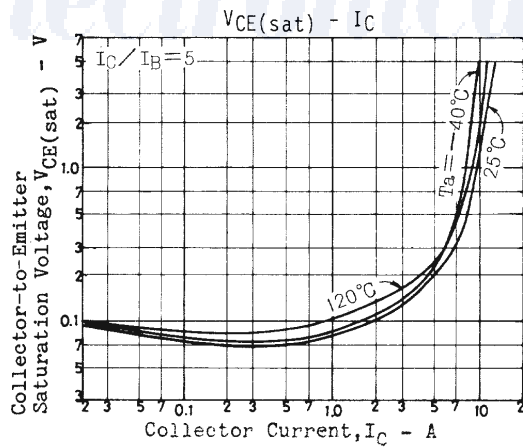
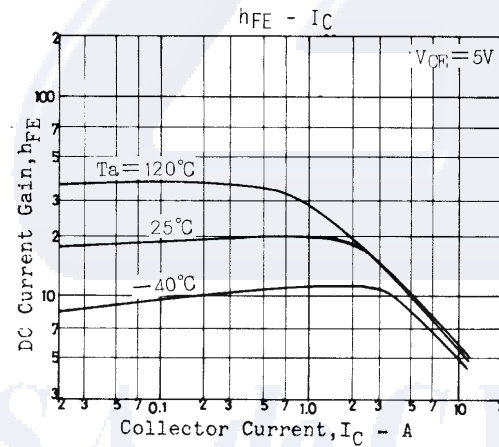
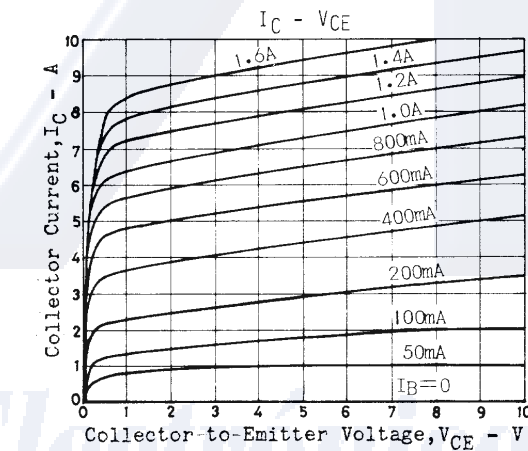
2SC3552

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|----------------|---|---------|-----|-----|---------|
| | | | min | typ | max | |
| Collector-to-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C=6A, I_B=1.2A$ | | | 2.0 | V |
| Base-to-Emitter Saturation Voltage | $V_{BE(sat)}$ | $I_C=6A, I_B=1.2A$ | | | 1.5 | V |
| Collector-to-Base Breakdown Voltage | $V_{(BR)CBO}$ | $I_C=1mA, I_E=0$ | 1100 | | | V |
| Collector-to-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | $I_C=5mA, R_{BE}=\infty$ | 800 | | | V |
| Emitter-to-Base Breakdown Voltage | $V_{(BR)EBO}$ | $I_E=1mA, I_C=0$ | 7 | | | V |
| Collector-to-Emitter Sustain Voltage | $V_{CEX(sus)}$ | $I_C=6A, I_{B1}=-I_{B2}=1.2A, L=500\mu H, \text{Clamped}$ | 800 | | | V |
| Turn-ON Time | t_{on} | $V_{CC}=400V, 5I_{B1}=-2.5I_{B2}=I_C=8A, R_L=500\Omega$ | | | 0.5 | μs |
| Storage Time | t_{stg} | $V_{CC}=400V, 5I_{B1}=-2.5I_{B2}=I_C=8A, R_L=500\Omega$ | | | 3.0 | μs |
| Fall Time | t_f | $V_{CC}=400V, 5I_{B1}=-2.5I_{B2}=I_C=8A, R_L=500\Omega$ | | | 0.3 | μs |

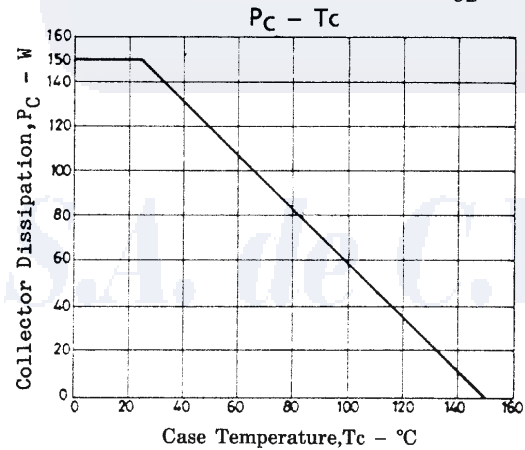
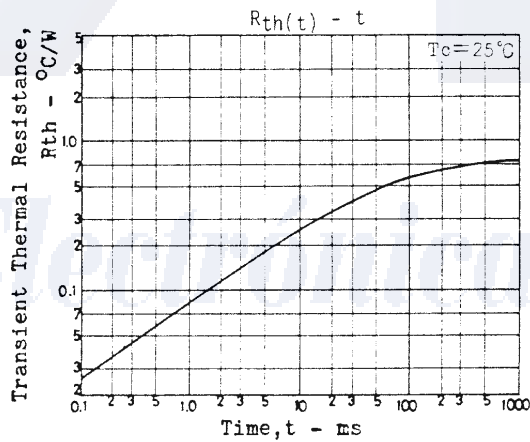
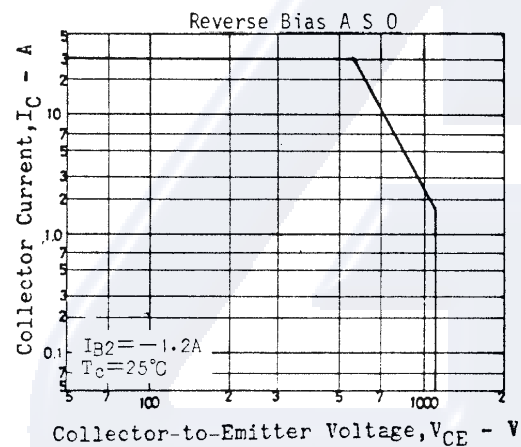
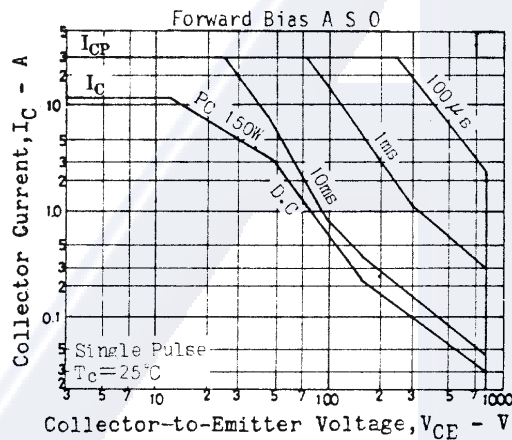
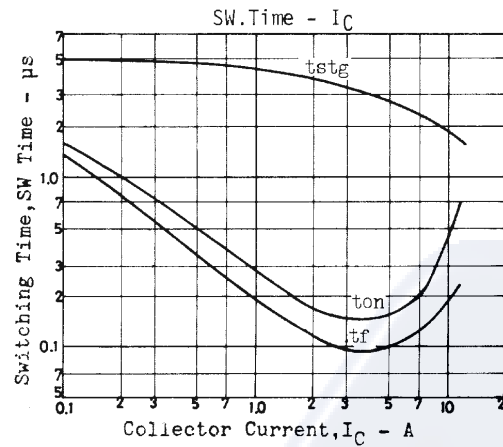
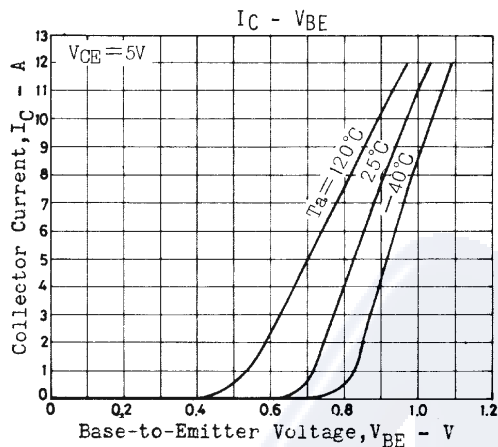
Switching Time Test Circuit



Unit (resistance : Ω , capacitance : F)



2SC3552



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